

Development of XUV multilayer coatings in IOF

Introduction

High-reflective XUV coatings are a key component for many applications including microscopy in the "water window" (2.3 - 4.4 nm), next generation lithography ($\lambda = 13.5 \text{ nm} / \lambda = 6. \text{X nm}$), high-order harmonic generation (20 - 50 nm), astronomy and spectroscopy (5 - 80 nm) as well as plasma diagnostics and laser research.

At the Fraunhofer IOF Jena multilayer coating development covers the full spectral range from 1.0 nm to vacuum ultraviolet around 200 nm. This paper covers some theoretical design considerations, prospects of modern interface-engineered strategies (interface barriers and capping layers) and deposition techniques for controlled fabrication of XUV multilayer coatings. The paper summarizes our recent progress in preparation of high-reflective multilayer coatings with regard to minimum structure imperfections, enhanced stability and different possibilities in broadening of the angular reflective response.

Deposition techniques

NESSY 1 (2003)



- Base pressure <math>< 10^{-8}</math> Torr
- Number of targets 4
- Optics size $\leq \varnothing 600$

NESSY 2 (2010)



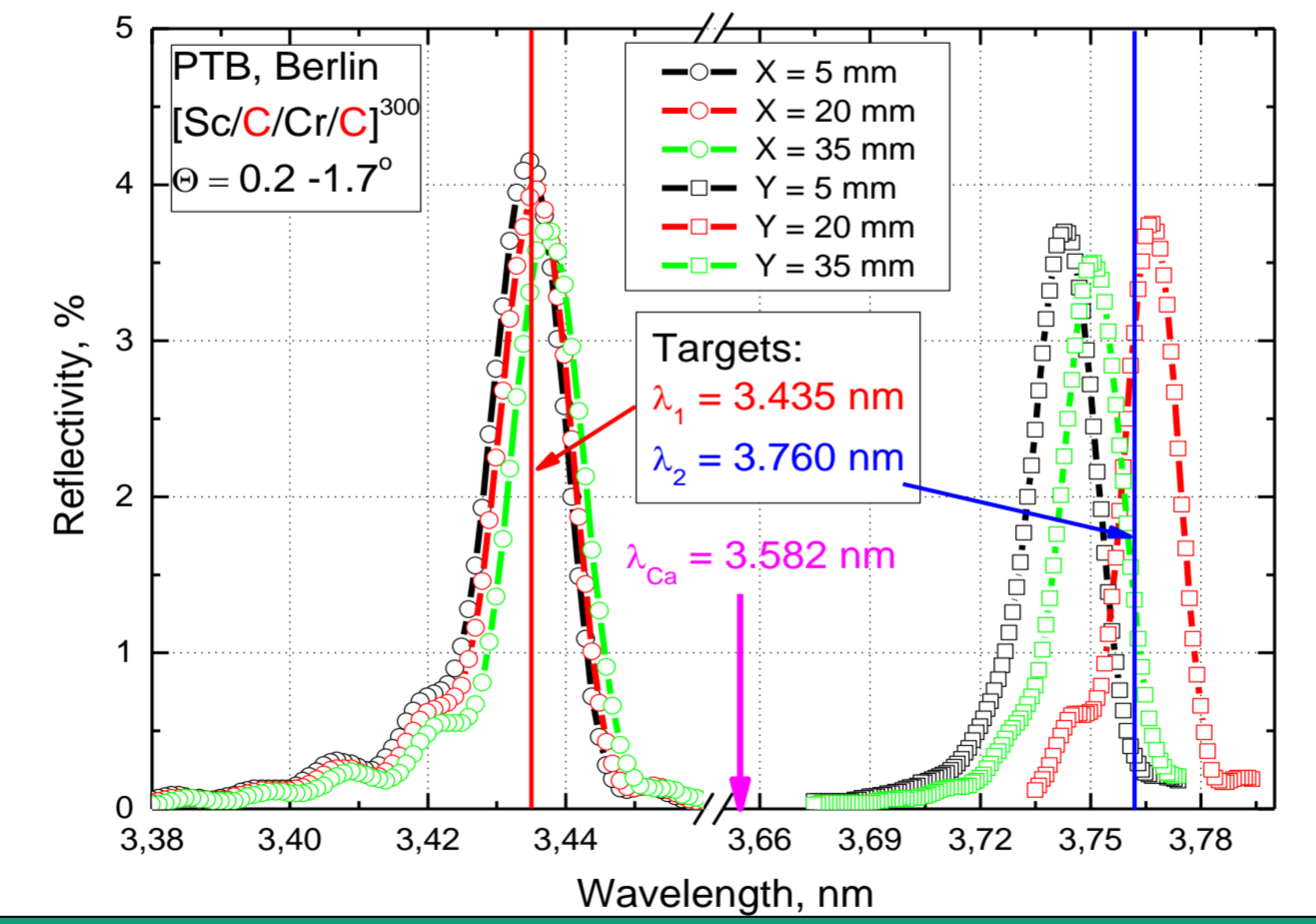
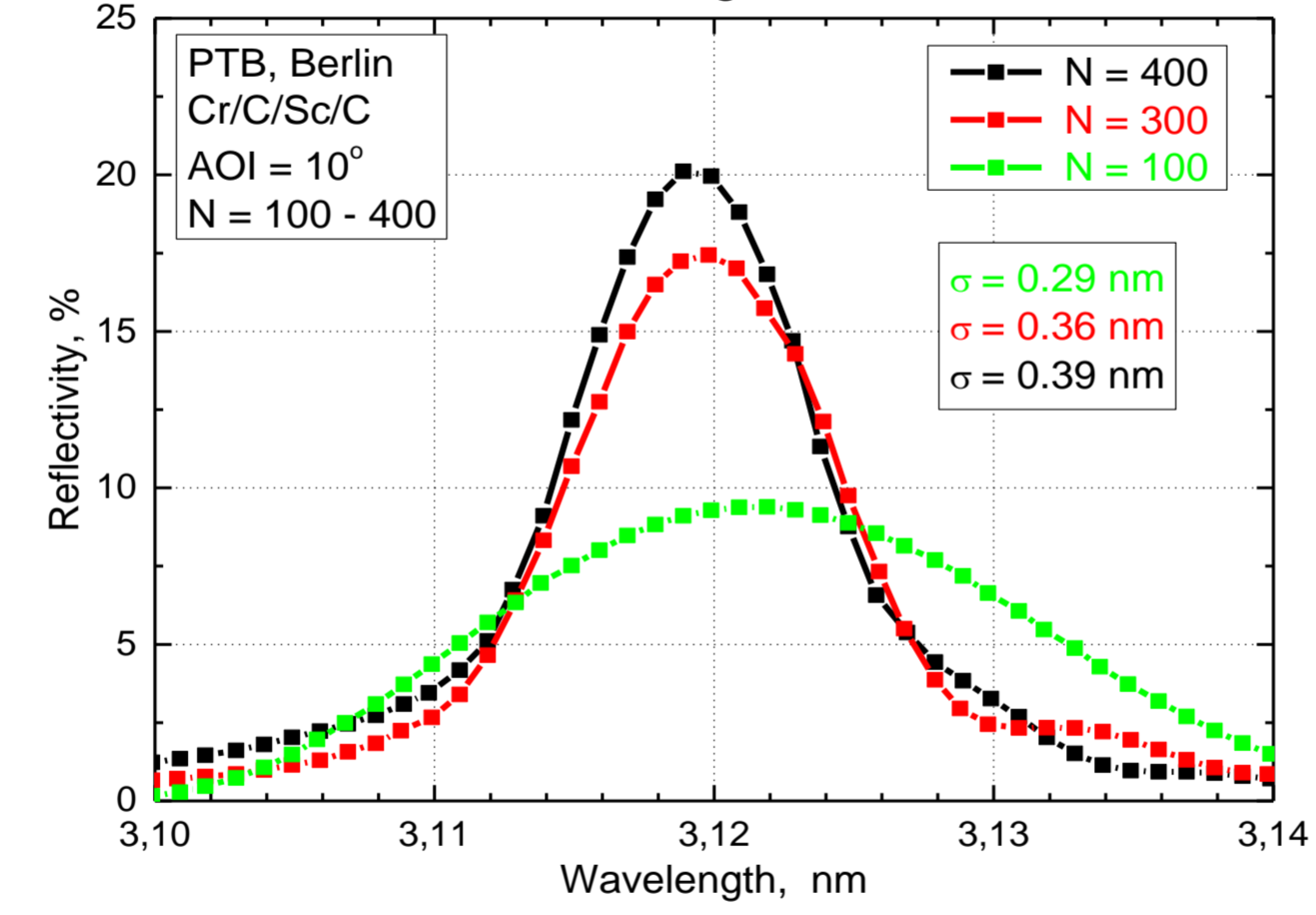
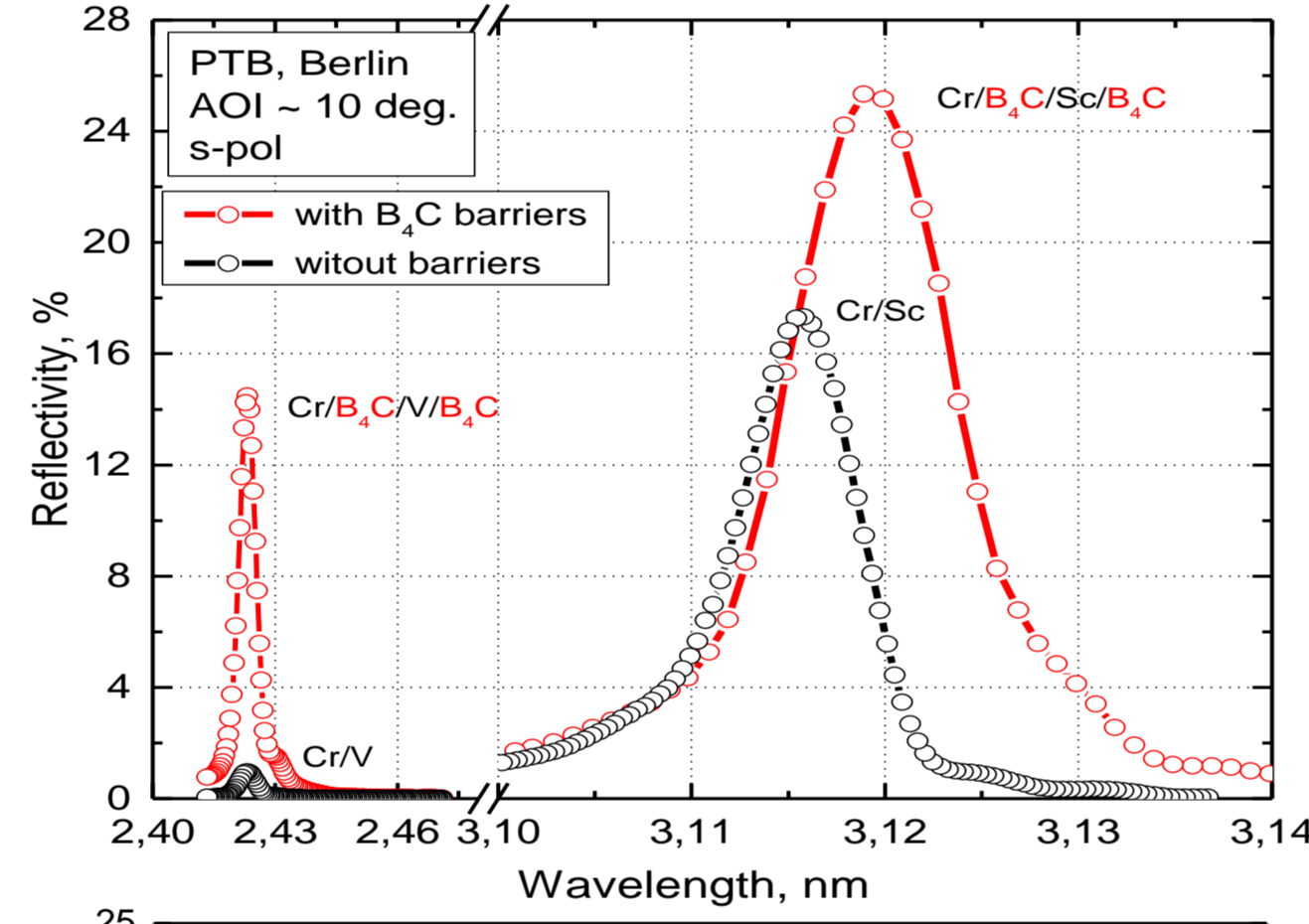
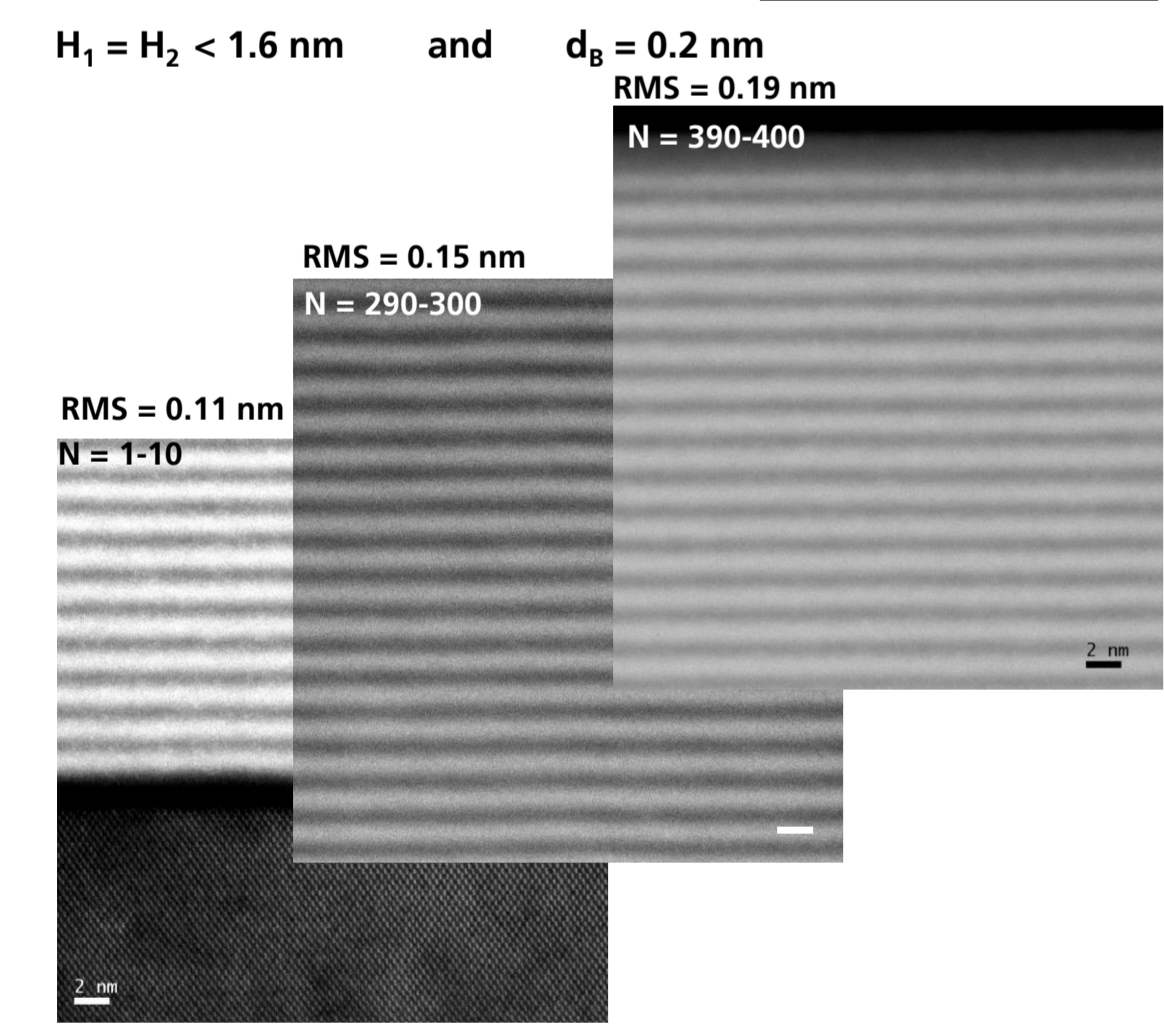
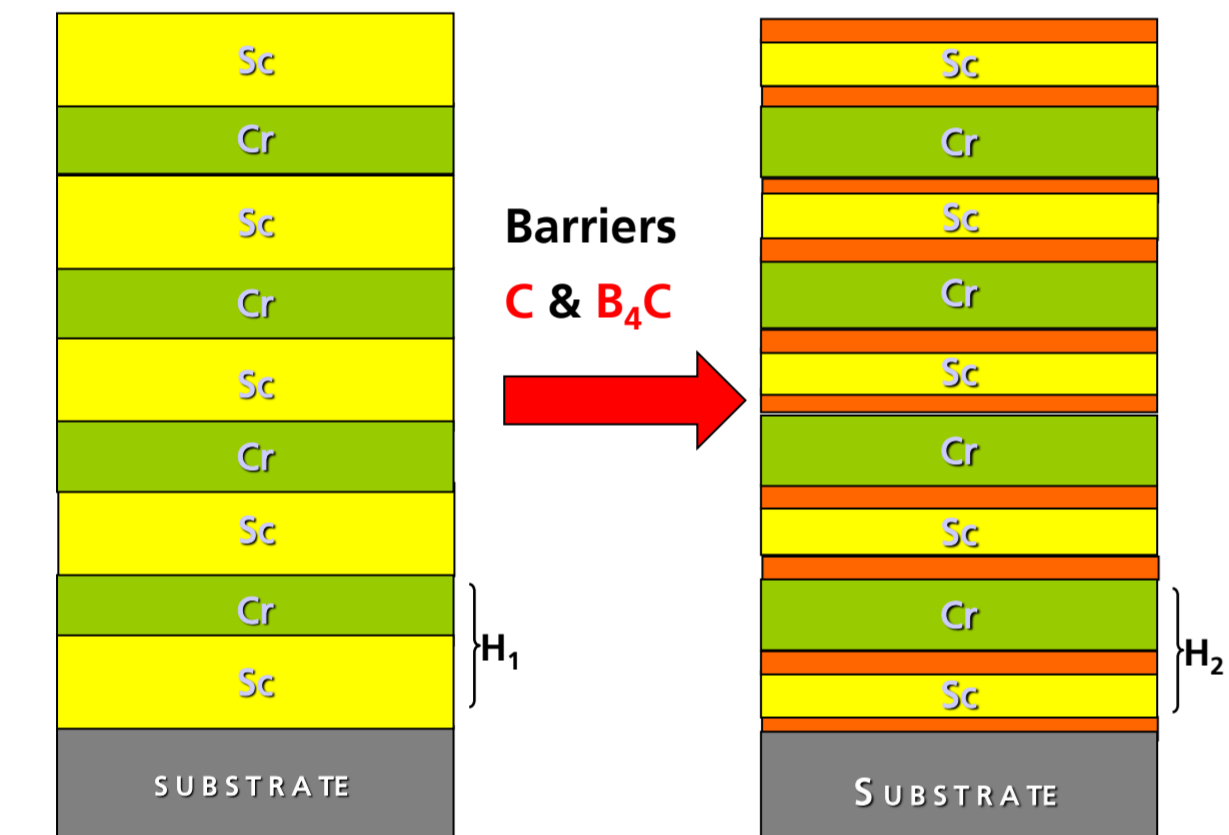
- Base pressure <math>< 10^{-8}</math> Torr
- Number of targets 6
- Optics size $\leq \varnothing 600$

NESSY 3 (2013)



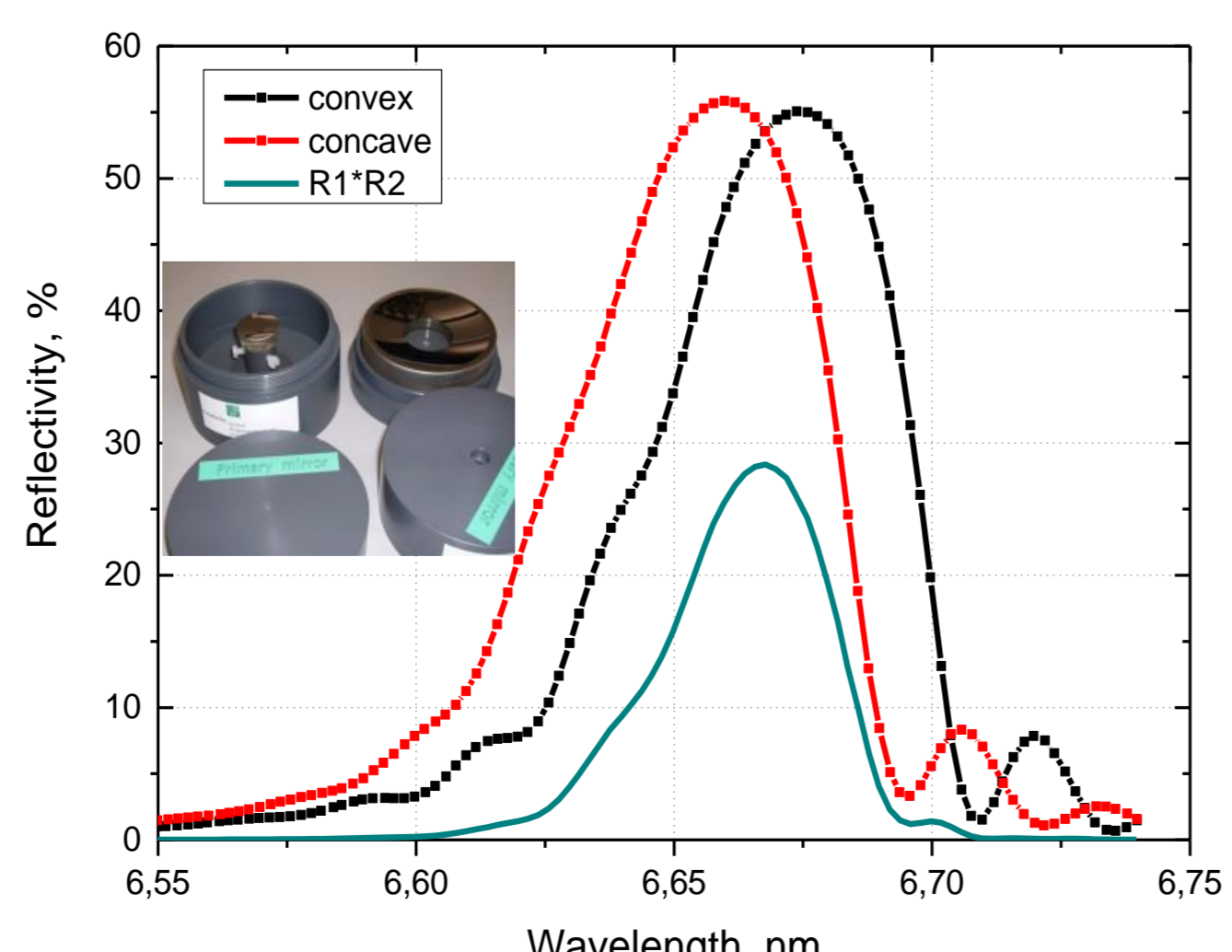
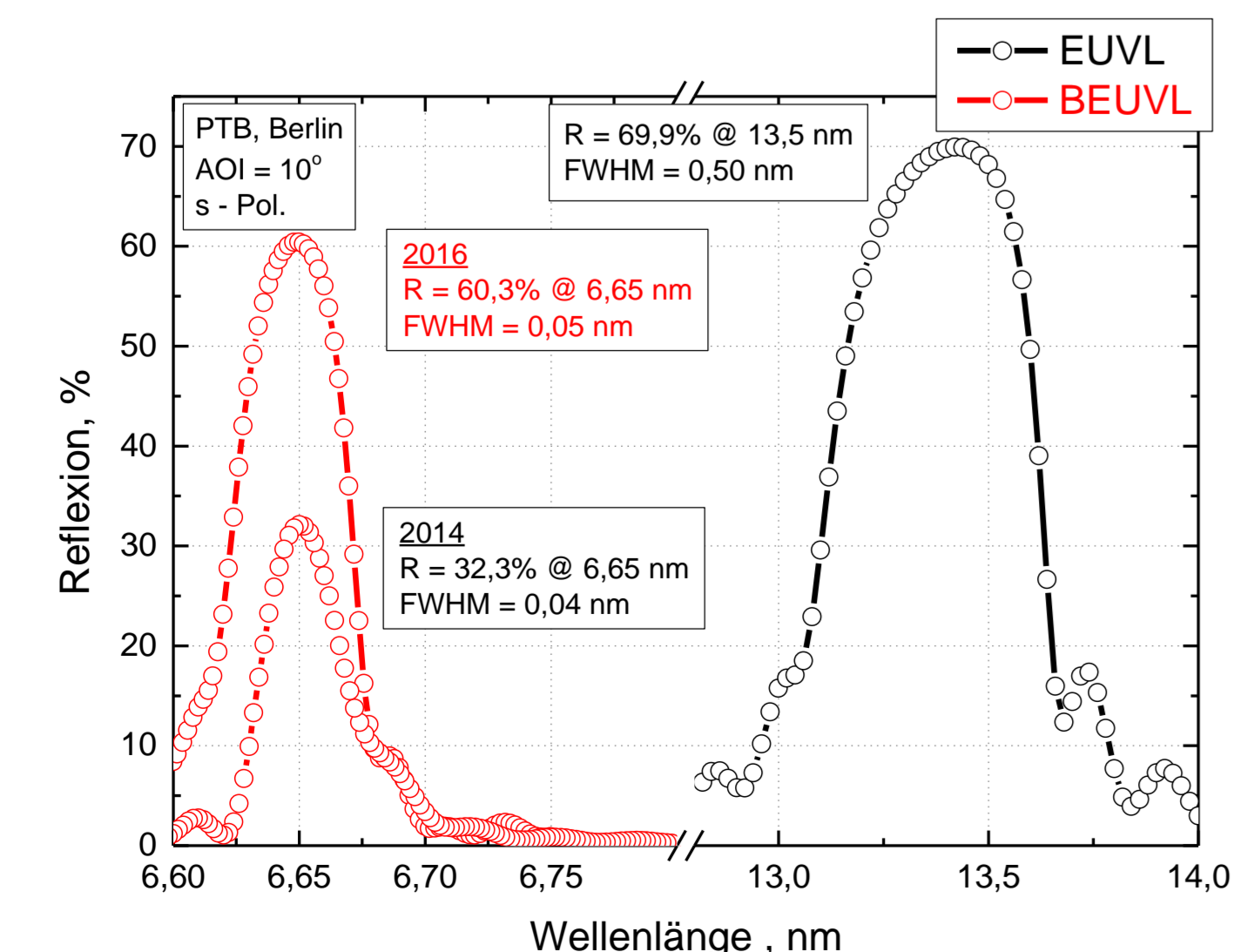
- Base pressure <math>< 8 \times 10^{-9}</math> Torr
- Number of targets 6
- Optics size $\leq \varnothing 200$

Multilayer coatings for microscopy in the water window (2.3...4.4 nm)



Multilayer coatings for next generation lithography (6.X and 13.5 nm)

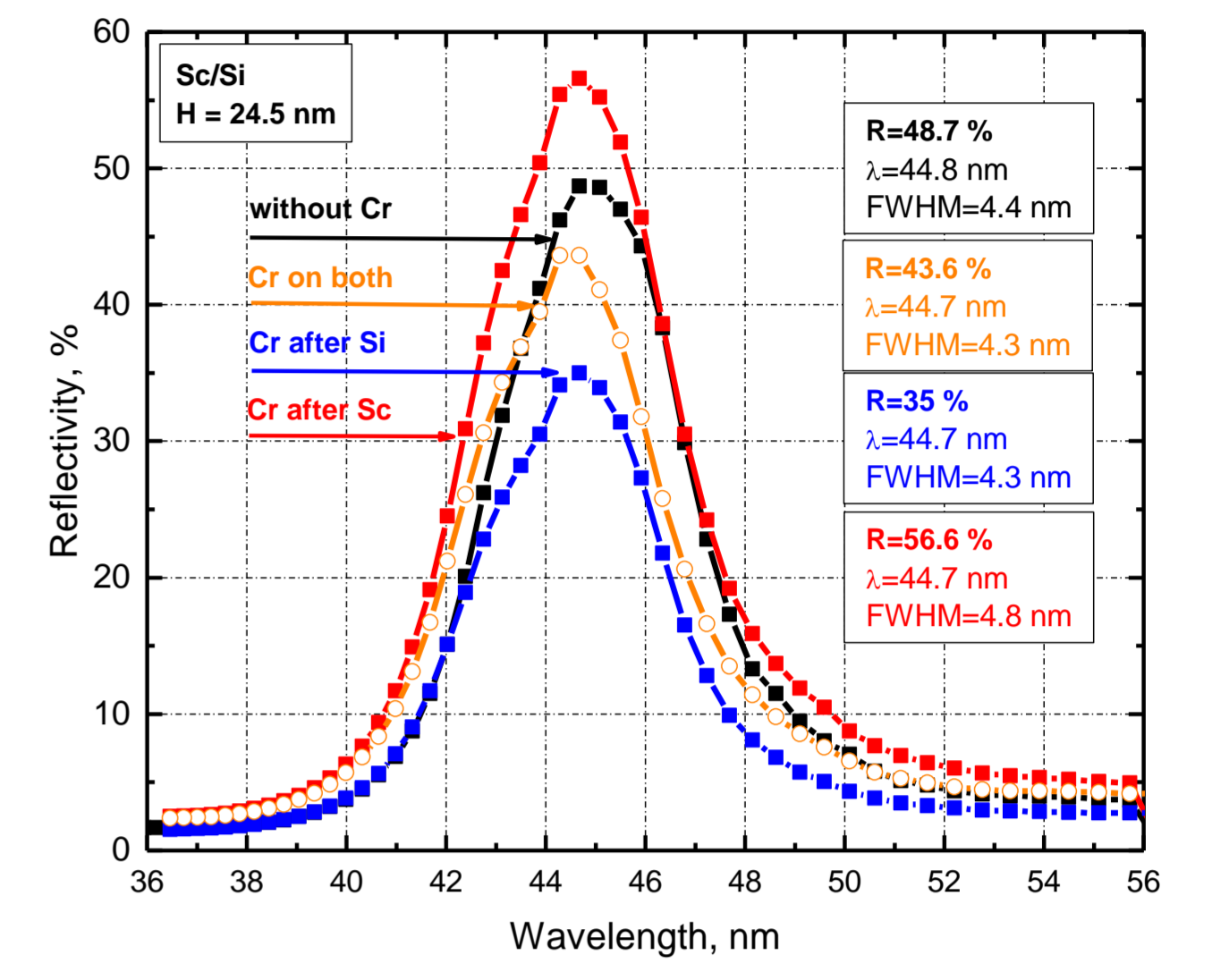
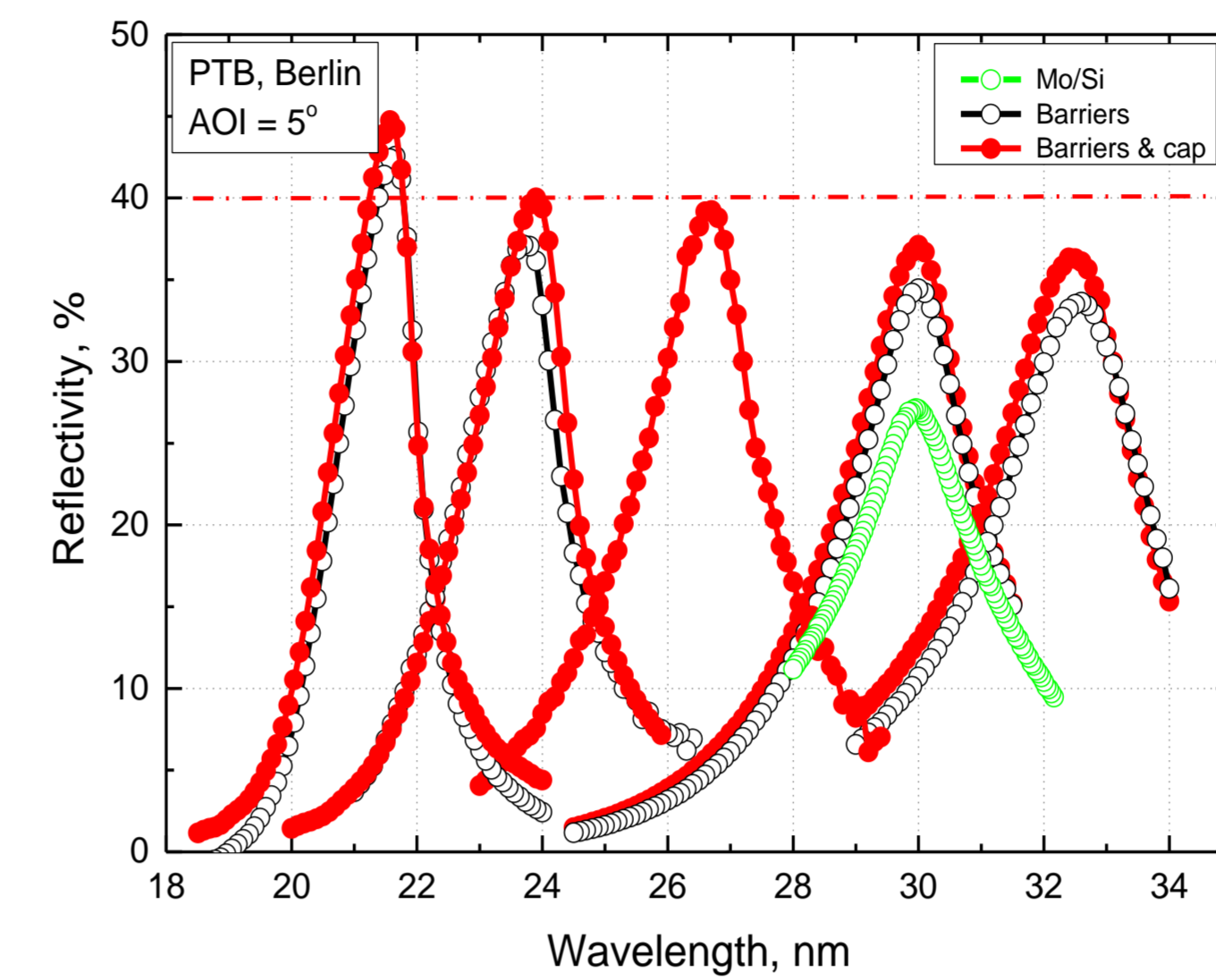
- Reflectivity improvement & wavelength matching (Schwarzschild objective @ 6.67 nm)



- Actual challenges:**
- $R > 72\%$ @ 13.5 nm and $R > 65\%$ @ 6.65 nm
 - FWHM > 0.1 nm @ 6.65 nm
 - Efficient grazing incidence coatings for 6.7 nm

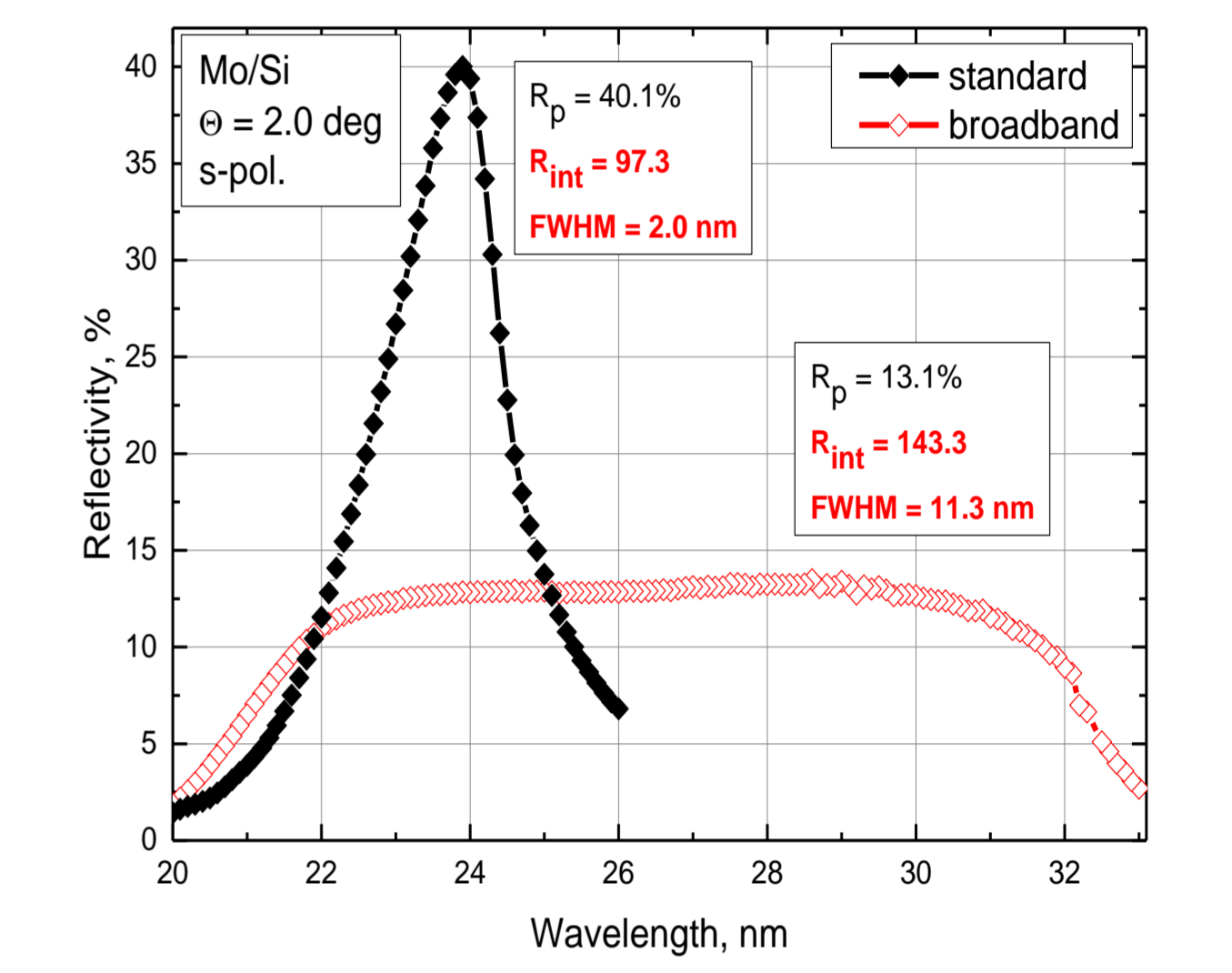
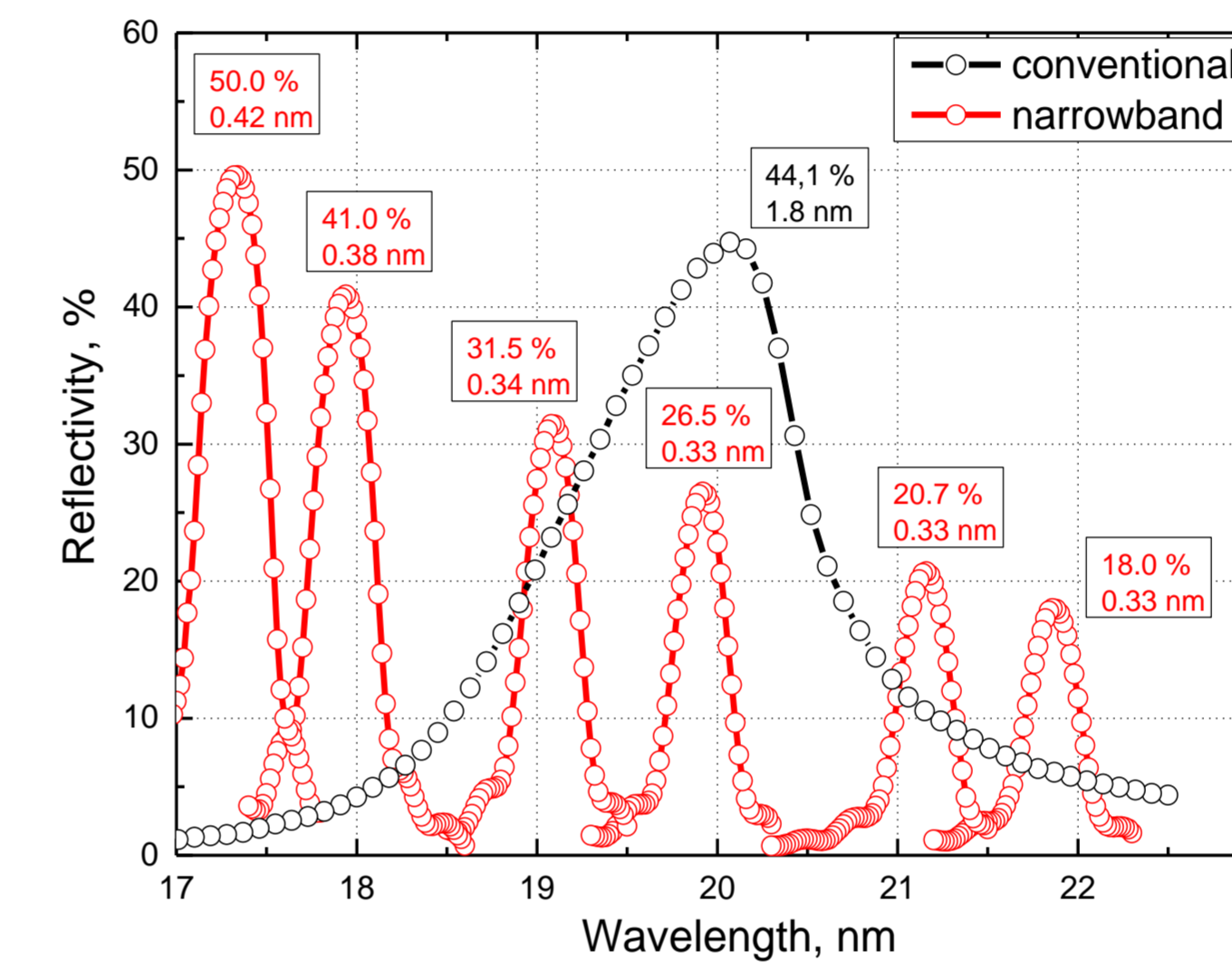
Multilayer coatings for high harmonics generation (15... 60 nm)

- Reflectivity enhancement by interface-engineering (barriers & capping layers)



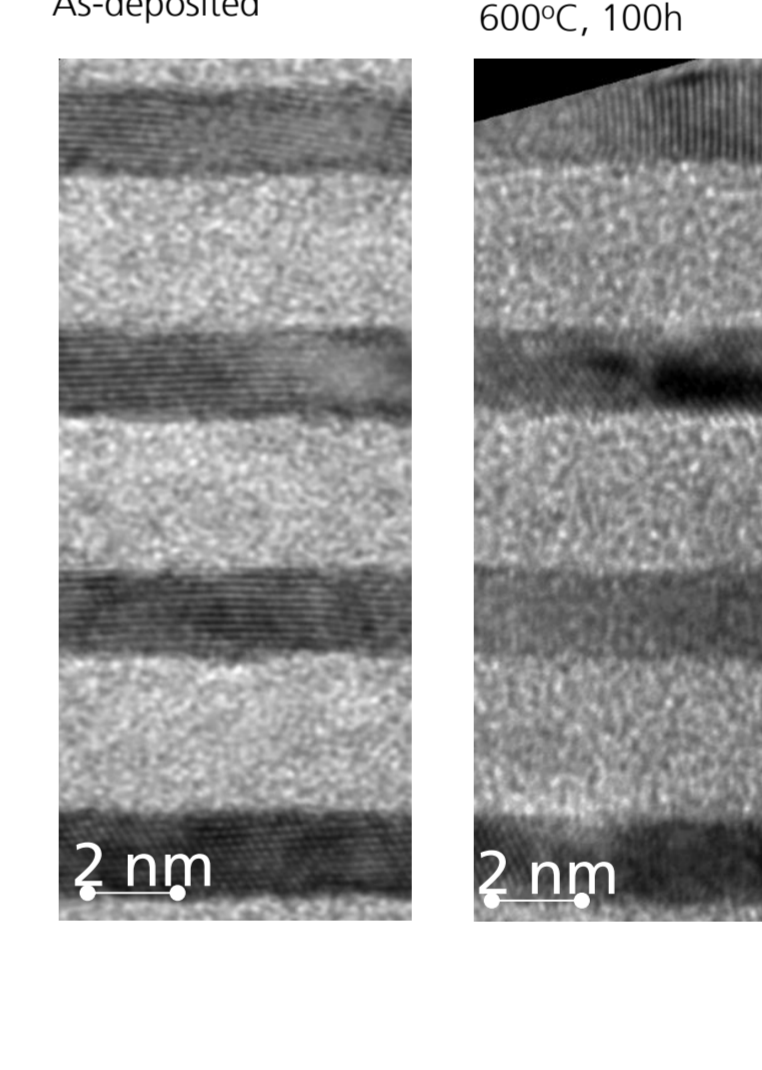
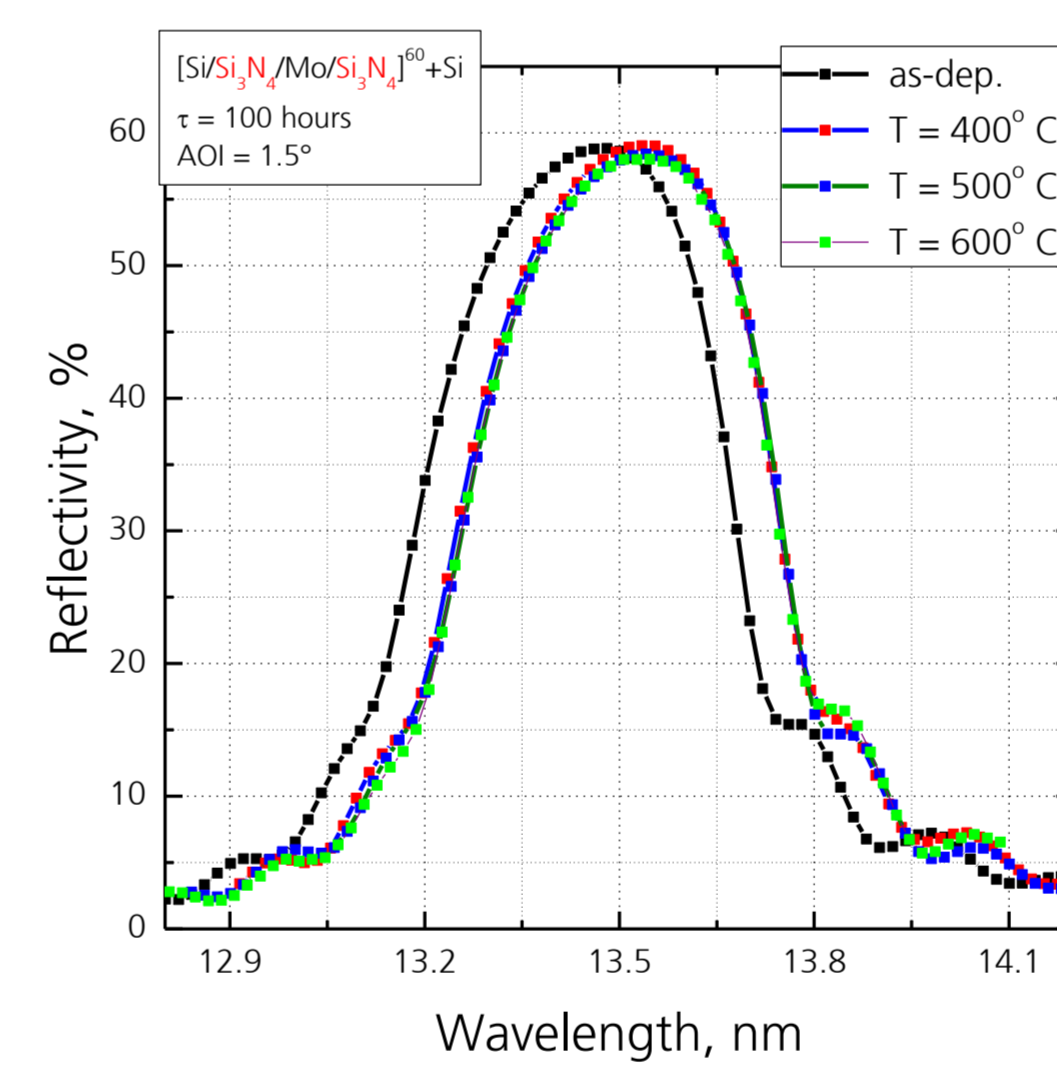
Actual challenges:

- narrowband (FWHM < 1.0 nm) and broadband (FWHM > 5.0 nm) coatings
- radiation stability



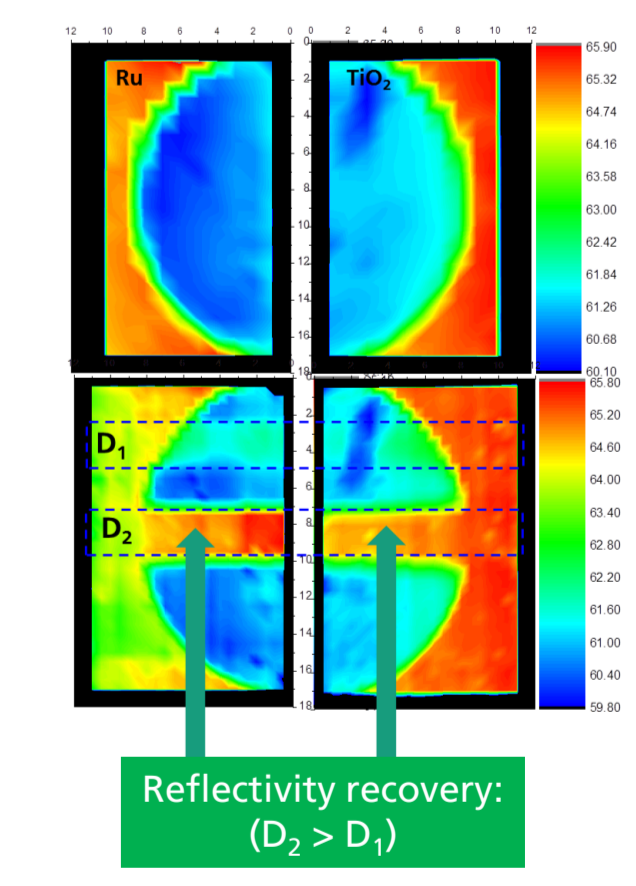
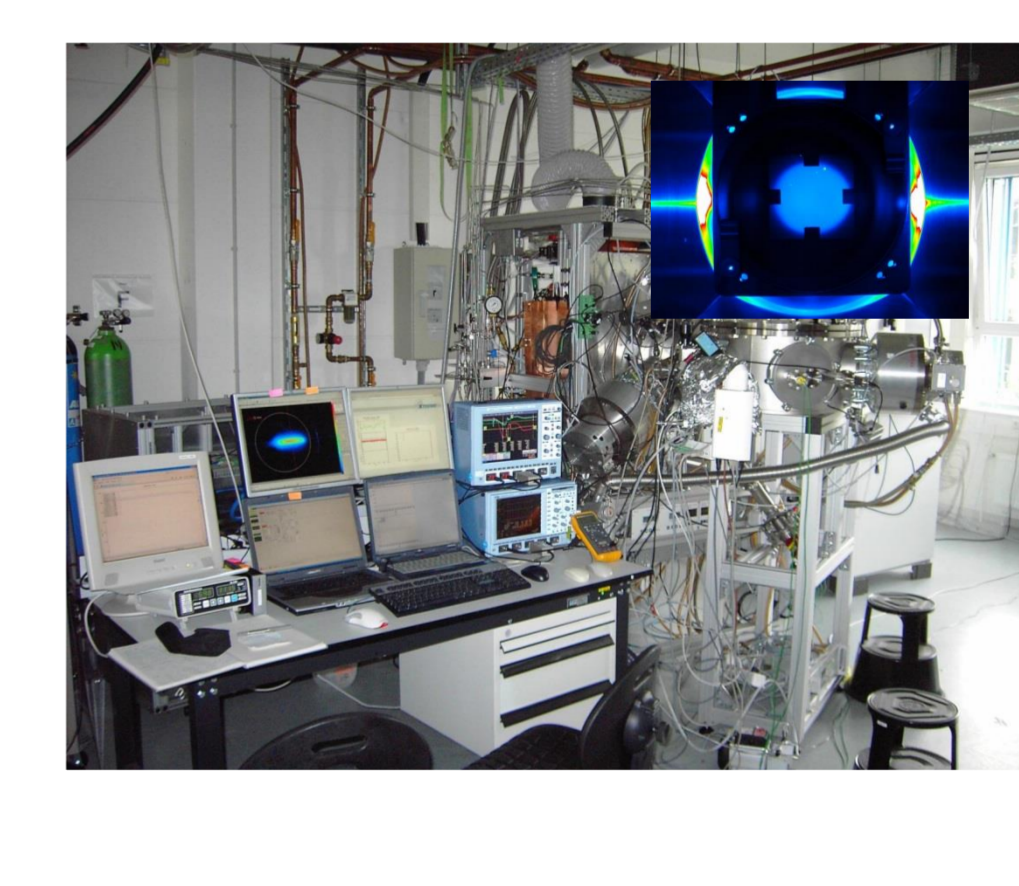
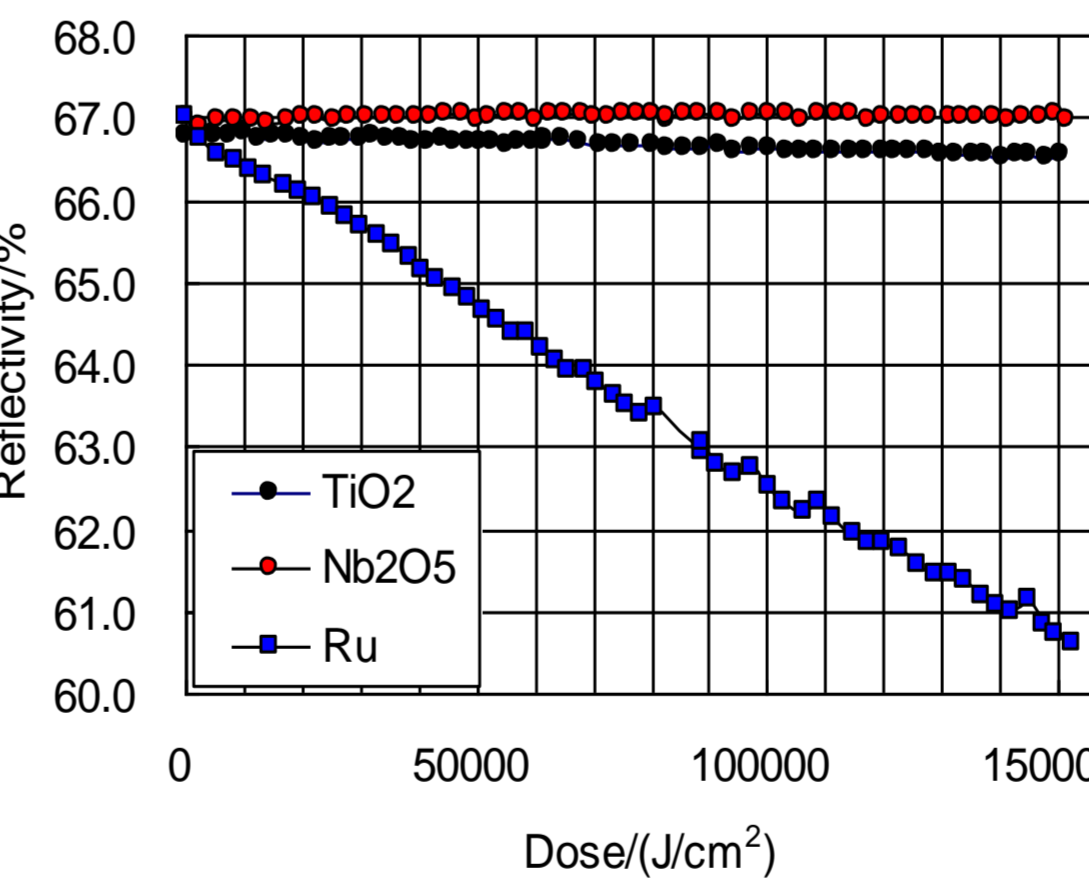
Multilayer coatings with enhanced stability

- Improvement of thermal stability by utilization of new materials and diffusion barriers



System	T_{max} °C	R_{max} %
Mo/Si	< 100	69
Mo ₂ C/Si	≤ 350	67
Mo/C/Si/C	≤ 400	60
MoSi ₂ /Si	≤ 600	42
Mo/Si ₃ N ₄ /Si/Si ₃ N ₄	≤ 600	60

- Improvement of optics lifetime by utilization of capping layers and surface cleaning technologies



Summary

- Remarkable progress has been made in Fraunhofer IOF in the field of XUV multilayer coatings for different applications
 - Microscopy
 - Cr/V and Cr/Sc multilayers 14.2% @ 2.42nm and 25.2% @ 3.11 nm
 - Lithography
 - La/Nb and Mo/Si multilayers 60.3% @ 6.65 nm and 69.9% @ 13.5 nm
 - HHG and astrophysics
 - Mo/Si and Sc/Si multilayers > 40 % @ 20...50 nm & narrowband / broadband
- Interface-engineering (barriers & capping layers) is the key-technology for improvement of optical performance and environmental stability of XUV multilayer coatings

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